Amplifier Transistors

NPN Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector - Emitter Voltage	BC546 BC547 BC548	V _{CEO}	65 45 30	Vdc
Collector - Base Voltage	BC546 BC547 BC548	V _{CBO}	80 50 30	Vdc
Emitter - Base Voltage		V_{EBO}	6.0	Vdc
Collector Current – Continuous		I _C	100	mAdc
Total Device Dissipation @ T _A = 2 Derate above 25°C	25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 2 Derate above 25°C	25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range		T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

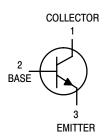
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

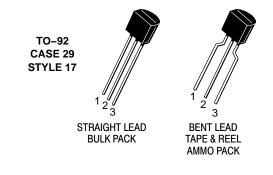
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



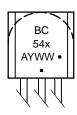
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



x = 6, 7, or 8

A = Assembly Location

Y = Year

WW = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			ļ.	ļ		1
Collector – Emitter Breakdown Voltage		V _{(BR)CEO}				V
$(I_C = 1.0 \text{ mA}, I_B = 0)$	BC546	(511)020	65	_	_	
	BC547		45	_	_	
	BC548		30	_	_	
Collector – Base Breakdown Voltage	DOE 40	$V_{(BR)CBO}$	00			V
$(I_C = 100 \mu\text{Adc})$	BC546 BC547		80 50	_	_	
	BC548		30	_	_	
Emitter – Base Breakdown Voltage		V _{(BR)EBO}				V
$(I_E = 10 \mu A, I_C = 0)$	BC546	(BIV)LBO	6.0	_	_	
	BC547		6.0	-	_	
	BC548		6.0	_	_	
Collector Cutoff Current		I _{CES}				
$(V_{CE} = 70 \text{ V}, V_{BE} = 0)$	BC546		_	0.2	15	nA
$(V_{CE} = 50 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 35 \text{ V}, V_{BE} = 0)$	BC547 BC548		_	0.2 0.2	15 15	
$(V_{CE} = 30 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 30 \text{ V}, T_{A} = 125^{\circ}\text{C})$	BC546/547/548		_	-	4.0	μΑ
ON CHARACTERISTICS			1			1
DC Current Gain		h				
$(I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{V})$	BC547A	h_{FE}	_	90	_	_
(i.e. i.e km i, i.e. e.e. i.)	BC546B/547B/548B		_	150	_	
	BC548C		_	270	_	
(1 20 - 1)	DCE46		110		450	
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC546 BC547		110 110	_	450 800	
	BC548		110	_	800	
	BC547A		110	180	220	
	BC546B/547B/548B		200	290	450	
	BC547C/BC548C		420	520	800	
$(I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC547A/548A		_	120	_	
(IC = 100 IIIX, VCE = 0.0 V)	BC546B/547B/548B		_	180	_	
	BC548C		_	300	_	
Collector – Emitter Saturation Voltage		V _{CE(sat)}				V
$(I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA})$		3 = (53)	_	0.09	0.25	
$(I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA})$			_	0.2	0.6	
(I _C = 10 mA, I _B = See Note 1)			_	0.3	0.6	
Base – Emitter Saturation Voltage		$V_{BE(sat)}$	_	0.7	_	V
$(I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA})$						
Base – Emitter On Voltage		$V_{BE(on)}$				V
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$			0.55	-	0.7	
$(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V})$			_	_	0.77	
SMALL-SIGNAL CHARACTERISTICS						
Current - Gain - Bandwidth Product		f_T				MHz
$(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz})$	BC546		150	300	_	
	BC547 BC548		150 150	300 300	_	
	DC340		130		_	
Output Capacitance $(V_{CB} = 10 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz})$		C_{obo}	_	1.7	4.5	pF
Input Capacitance		C_{ibo}	_	10	_	pF
$(V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz})$						
Small – Signal Current Gain		h _{fe}				-
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ kHz})$	BC546		125	_	500	
	BC547/548 BC547A		125 125	220	900 260	
	BC546B/547B/548B		240	330	500	
	BC547C/548C		450	600	900	
Noise Figure ($I_C = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ V}, R_S = 2 \text{ k}\Omega, f = 0.0 \text{ mA}$	= 1 0 kHz Af = 200 Hz)	NF				dB
140130 1 19016 (1C - 0.2 111M, VCE = 3.0 V, KS = 2 KS2, I =	$= 1.0 \text{ kHz}, \Delta I = 200 \text{ Hz})$ $= 1.0 \text{ kHz}, \Delta I = 200 \text{ Hz})$	INI	_	2.0	10	45
			_	2.0	10	
	BC547		_	2.0	10	

^{1.} I_B is value for which I_C = 11 mA at V_{CE} = 1.0 V.

BC547/BC548

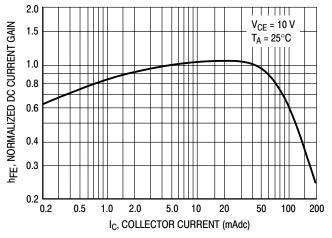


Figure 1. Normalized DC Current Gain

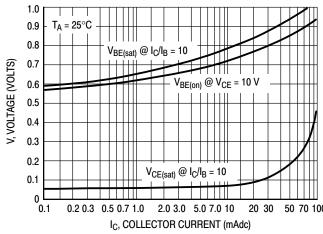


Figure 2. "Saturation" and "On" Voltages

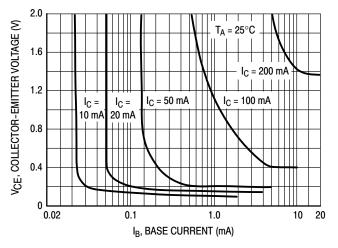


Figure 3. Collector Saturation Region

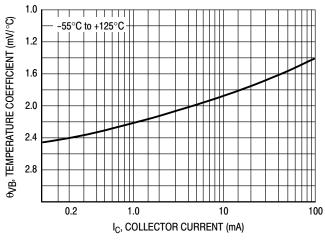


Figure 4. Base-Emitter Temperature Coefficient

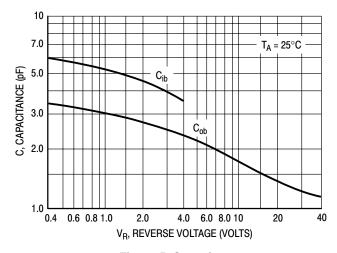


Figure 5. Capacitances

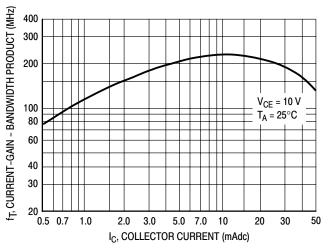


Figure 6. Current-Gain - Bandwidth Product

BC546

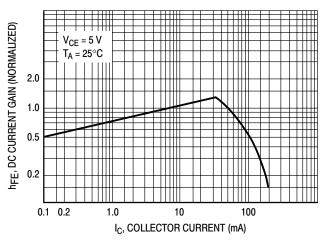


Figure 7. DC Current Gain

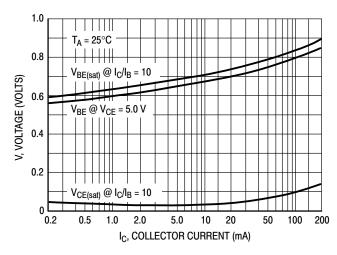


Figure 8. "On" Voltage

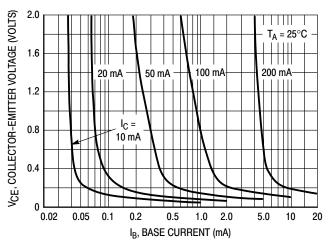


Figure 9. Collector Saturation Region

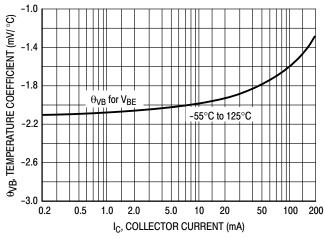


Figure 10. Base-Emitter Temperature Coefficient

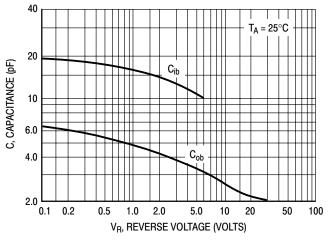


Figure 11. Capacitance

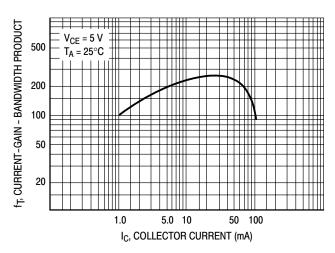


Figure 12. Current-Gain - Bandwidth Product

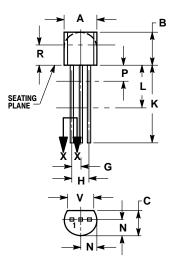
ORDERING INFORMATION

Device	Package	Shipping [†]
BC546B	TO-92	5000 Units / Bulk
BC546BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC546BRL1	TO-92	2000 / Tape & Reel
BC546BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC546BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547ARL	TO-92	2000 / Tape & Reel
BC547ARLG	TO-92 (Pb-Free)	2000 / Tape & Reel
BC547AZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC547BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC547BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC547CG	TO-92 (Pb-Free)	5000 Units / Bulk
BC547CZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC548BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC548BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC548BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC548CG	TO-92 (Pb-Free)	5000 Units / Bulk
BC548CZL1G	TO-92 (Pb-Free)	2000 / Ammo Box

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM

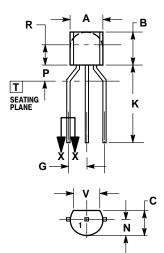


STRAIGHT LEAD **BULK PACK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
V	0 135		3 43	



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
 DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
C	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
7	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
٧	3.43		

STYLE 17:

COLLECTOR PIN 1.

BASE

EMITTER

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